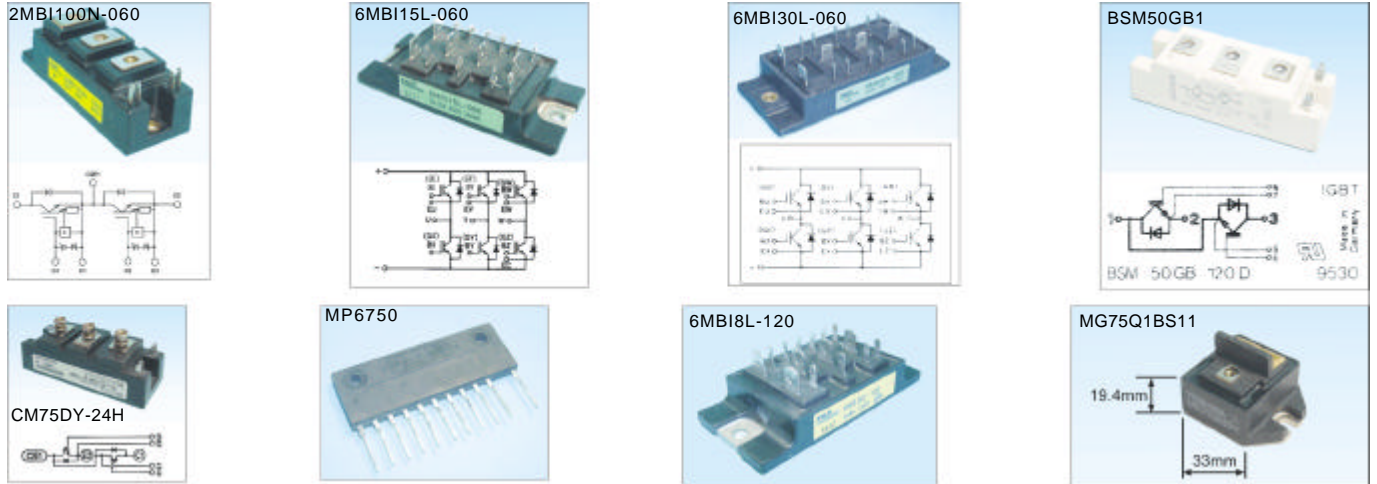


SEMICONDUCTORS-DISCRETES

PartNo.	ProductNo.	Manuf.	Description	Pd(max)/W	Vces	Ic(A)	Pins/Package
27908	IRG4PC30U	IR	IGBT 晶體	100W	600V	12A	3P/TO-247
23349	IRG4PC30UD	IR	UltraFast CoPack IGBT	100W	600V	12A	3P/TO-247

IGBT 模塊 IGBT Modules

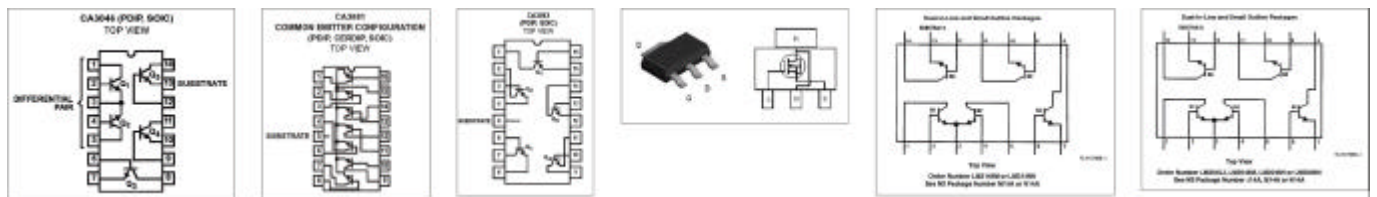
詳細產品規格--請點擊www.100y.com.tw



PartNo	ProductNo.	Manuf.	Description	Pd(max)/W	Vces	Ic(A)	Package
16523	2MBI100N-060	Fuji Elect	IGBT 模塊 (2U)		600V	100A	
16519	6MBI15L-060	Fuji Elect	IGBT 模塊 (6U)		600V	15A	
16627	6MBI30L-060	Fuji Elect	IGBT 模塊 (6U)		600V	30A	
17294	6MBI8L-120	Fuji Elect	IGBT 模塊 (6U)		1200V	8A	module
16520	BSM50GB1	SIEMENS	IGBT power module (2U)		1200V	74A	
16521	CM75DY-24H	MITSUBISHI	Dual IGBT 模塊 (2U)		1200V	75A	
27244	MCD44-16I08B	IXYS	Thyristor/Diode Modules	10W	1600V	51A	TO-240AA
16522	MG75Q1BS11	TOSHIBA	IGBT 高速型模塊 (1U)		1200V	75A	
17147	MP6750	TOSHIBA	IGBT 模塊	55W	600V	15A	module

電晶體陣列IC 電晶體陣列 Transistor Arrays

詳細產品規格--請點擊www.100y.com.tw



PartNo.	ProductNo.	Manuf.	Description	Pins/Package
1260	CA3046	HARRIS	General Purpose NPN Transistor Array	14P/DIP
1261	CA3081	HARRIS	General purpose high current NPN transistor array	16P/DIP
1262	CA3083E	HARRIS	General purpose high current NPN transistor array	16P/DIP
23445	CA3146E	HARRIS	High-Voltage Transistor Arrays	14P/DIP
15621	FDT439N	Fairchild	N-Channel 2.5V Specified Enhancement Mode Field Effect Transistor	4P/SOT-223
26016	LM3086N	Intersil	NPN transistor arrays	14P/DIP
3941	LM3086N	HARRIS	NPN transistor arrays	14P/DIP

兩極半導體(Diacs/Sidacs) 兩極半導體(DIACS) DIAC Silicon Bi-directional Trigger Diodes

詳細產品規格--請點擊www.100y.com.tw

FEATURES:
Vbo: 32V and 40V

LOW BREAKOVER CURRENT

PartNo	ProductNo.	Manuf.	Description	Vbo	Itrms(A)	Package
8188	DB-3	ST(SGS)	Triac Trigger Device	28 to 36V	2A	DO-35

